



# SANYO SEMICONDUCTOR

## DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS

<b>NPN</b>	<b>PNP</b>
TIP640	TIP645
TIP641	TIP646
TIP642	TIP647

60-80-100 VOLTS, 10 AMPERE

HIGH CURRENT GAIN  $h_{FE} = 4000$  typ. @ 3V, 5A  
 LOW SATURATION VOLTAGE  $V_{CE(SAT)} = 1.0V$  typ. @ 5A  
 MONOLITHIC CONSTRUCTION WITH BUILT-IN  
 (1) BASE-EMITTER RESISTORS AND  
 (2) COLLECTOR-EMITTER DIODE

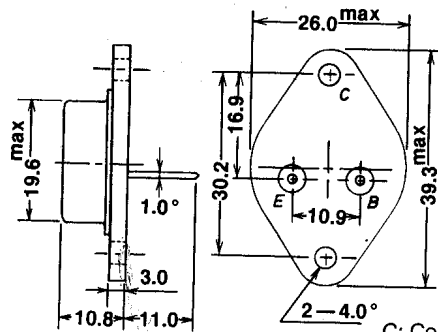
### ABSOLUTE MAXIMUM RATINGS @ $T_a = 25^\circ C$

RATING	SYMBOL	TIP640, TIP645	TIP641, TIP646	TIP642, TIP647	UNIT
COLLECTOR-EMITTER VOLTAGE	$V_{CEO}$	60	80	100	Vdc
COLLECTOR-BASE VOLTAGE	$V_{CB}$	60	80	100	Vdc
EMITTER-BASE VOLTAGE	$V_{EB}$	← 5.0 →			Vdc
COLLECTOR CURRENT- CONTINUOUS PEAK	$I_C$	← 10 → ← 15 →			Adc
TOTAL POWER DISSIPATION @ $T_C = 25^\circ C$	$P_D$	← 175 →			W
TOTAL POWER DISSIPATION @ $T_A = 25^\circ C$	$P_D$	← 5 →			W
OPERATING AND STORAGE JUNCTION TEMPERATURE RANGE	$T_J, T_{stg}$	← - 55 to + 150 →			$^\circ C$

### OUTLINE DIMENSION

JEDEC: TO-3

UNIT: MM



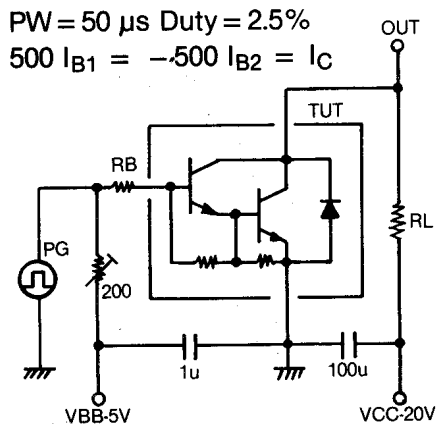
C: Collector  
 E: Emitter  
 B: Base

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 1535 Alps Road  
 WAYNE, NEW JERSEY 07470  
 (201) 696-3987 TWX 710-988-0703

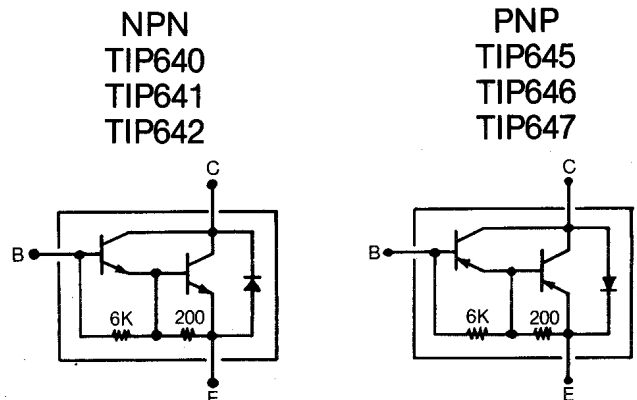
# ELECTRICAL CHARACTERISTICS @ Ta = 25°C

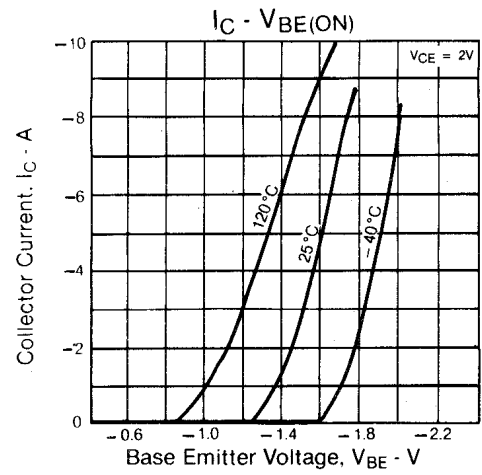
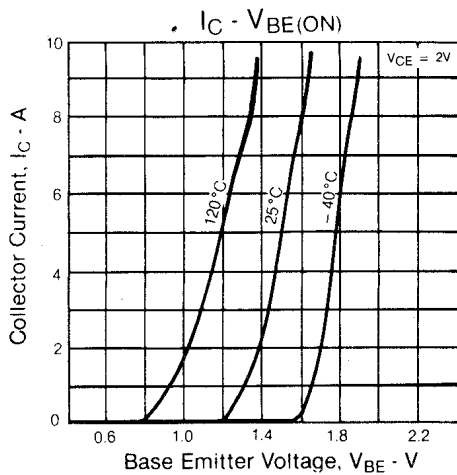
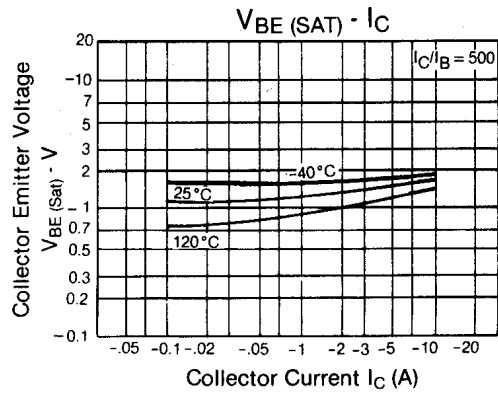
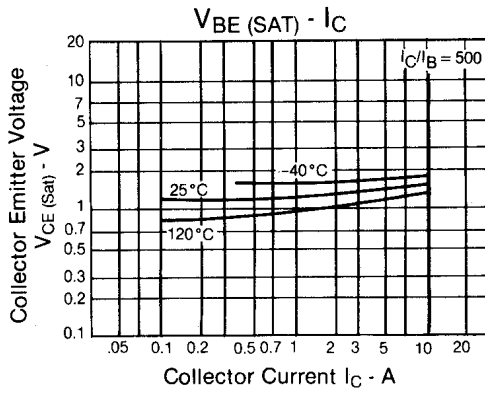
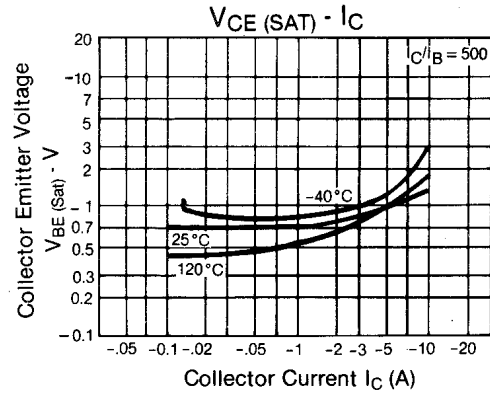
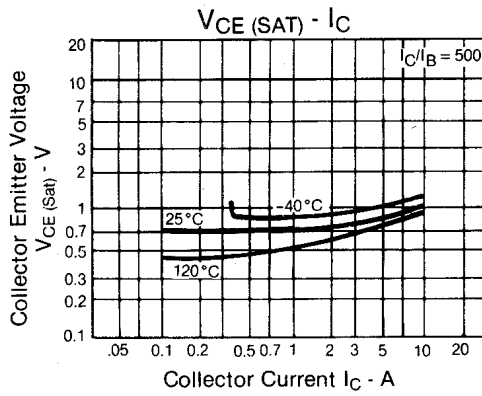
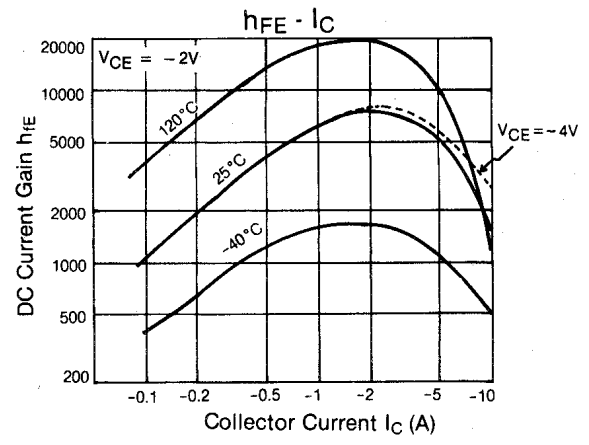
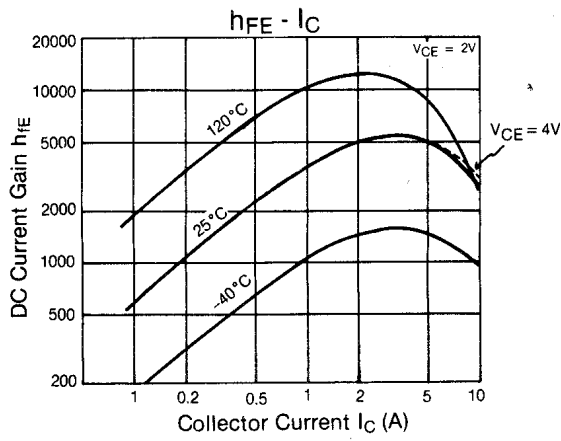
CHARACTERISTIC	SYMBOL	MIN	MAX	UNIT
COLLECTOR-EMITTER SUSTAINING VOLTAGE (I <sub>C</sub> = 30 mA, I <sub>B</sub> = 0) TIP640, TIP645 TIP641, TIP646 TIP642, TIP647	V <sub>CEO(SUS)</sub>	60 80 100	—	V <sub>dc</sub>
COLLECTOR CUTOFF CURRENT (V <sub>CE</sub> = 30 V <sub>dc</sub> , I <sub>B</sub> = 0) (V <sub>CE</sub> = 40 V <sub>dc</sub> , I <sub>B</sub> = 0) (V <sub>CE</sub> = 50 V <sub>dc</sub> , I <sub>B</sub> = 0) TIP640, TIP645 TIP641, TIP646 TIP642, TIP647	I <sub>CEO</sub>	— — —	2.0 2.0 2.0	mA <sub>dc</sub>
COLLECTOR CUTOFF CURRENT (V <sub>CB</sub> = 60 V <sub>dc</sub> , I <sub>E</sub> = 0) (V <sub>CB</sub> = 80 V <sub>dc</sub> , I <sub>E</sub> = 0) (V <sub>CB</sub> = 100 V <sub>dc</sub> , I <sub>E</sub> = 0) TIP640, TIP645 TIP641, TIP646 TIP642, TIP647	I <sub>CBO</sub>	— — —	1.0 1.0 1.0	mA <sub>dc</sub>
EMITTER CUTOFF CURRENT (V <sub>BE</sub> = 5.0 V <sub>dc</sub> , I <sub>C</sub> = 0)	I <sub>EBO</sub>	—	2.0	mA <sub>dc</sub> mA <sub>dc</sub>
DC CURRENT GAIN (I <sub>C</sub> = 5.0 A, V <sub>CE</sub> = 4.0 V <sub>dc</sub> ) (I <sub>C</sub> = 10.0 A, V <sub>CE</sub> = 4.0 V <sub>dc</sub> )	h <sub>FE</sub>	1000 500	— —	—
COLLECTOR-EMITTER SATURATION VOLTAGE (I <sub>C</sub> = 5.0 A, I <sub>B</sub> = 10 mA <sub>dc</sub> ) (I <sub>C</sub> = 10.0 A, I <sub>B</sub> = 40 mA <sub>dc</sub> )	V <sub>CE(SAT)</sub>	— —	2.0 3.0	V <sub>dc</sub>
BASE-EMITTER ON VOLTAGE (I <sub>C</sub> = 10.0 A, V <sub>CE</sub> = 4.0 V <sub>dc</sub> )	V <sub>BE(ON)</sub>	—	3.0	V <sub>dc</sub>
GAIN BANDWIDTH PRODUCT (I <sub>C</sub> = 5.0 A, V <sub>CE</sub> = 5.0V)	f <sub>T</sub>	20 typ.		mHz

## SWITCHING TIME TEST CIRCUIT

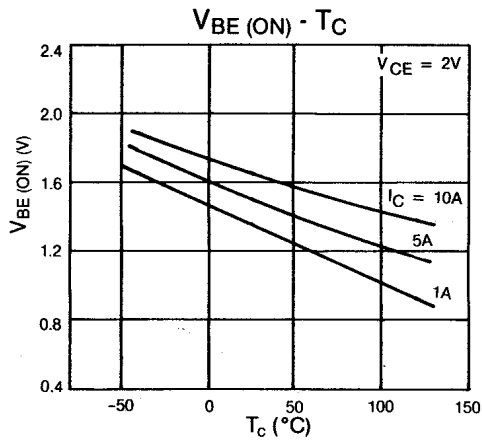
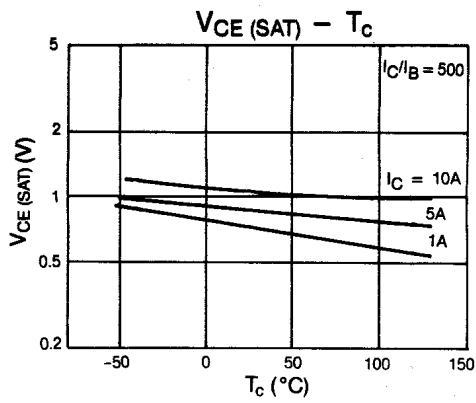
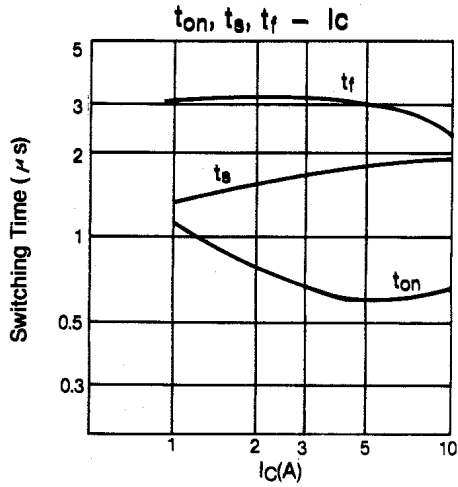


## DARLINGTON SCHEMATIC

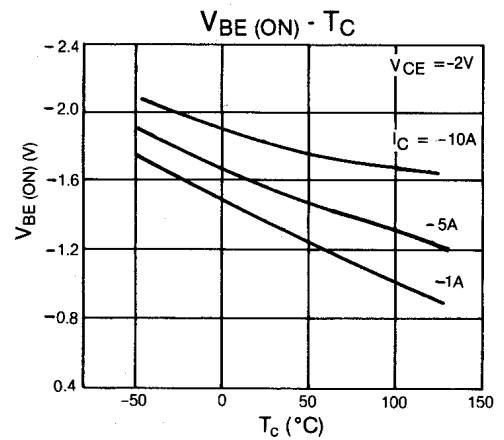
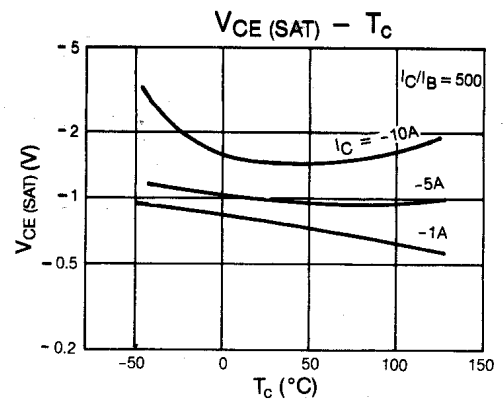
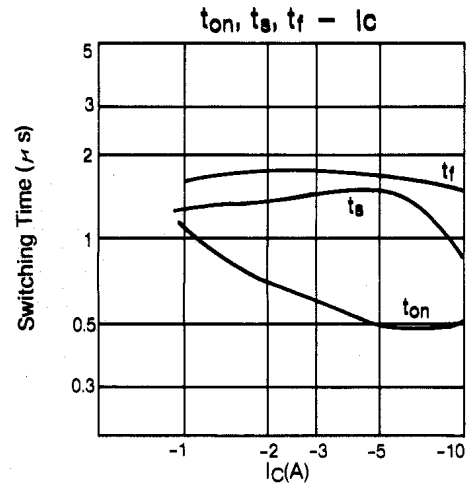




NPN  
TIP 640, TIP 641, TIP 642



PNP  
TIP 645, TIP 646, TIP 647



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